



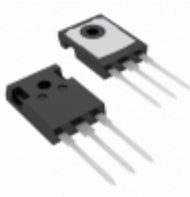

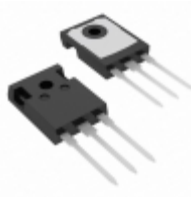
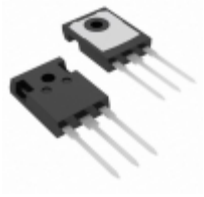

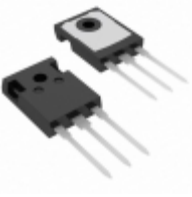

 	<h2 style="color: red;">FDH5500_F085</h2>
	Hersteller-Teilenummer: FDH5500_F085
	Hersteller / Marke: Fairchild/ON Semiconductor
	Teil der Beschreibung: FDH5500_F085 Fairchild/ON Semiconductor
	Datenblätter:  FDH5500_F085.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 23007 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FDH5500_F085
Hersteller	Fairchild/ON Semiconductor
Beschreibung	FDH5500_F085 Fairchild/ON Semiconductor
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	23007 pcs Stock
Serie	Automotive, AEC-Q101, UltraFET™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Verlustleistung (max)	375W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	55V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	75A (Tc)
Rds On (Max) @ Id, Vgs	7 mOhm @ 75A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	268nC @ 20V
Eingabekapazität (Ciss) (Max) @ Vds	3565pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube

FDH5500_F085 ist neu im Original, Suche FDH5500_F085 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FDH5500_F085 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FDH5500_F085: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FDH600 AMI Semiconductor / ON Semiconductor DIODE GEN PURP 50V 200MA DO35</p>	 <p>FDH50N50_F133 Fairchild/ON Semiconductor FDH50N50_F133 Fairchild/ON Semiconductor</p>	 <p>FDH600 Fairchild/ON Semiconductor DIODE GEN PURP 50V 200MA DO35</p>	 <p>FDH50N50-F133 AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 48A TO-247</p>
 <p>FDH5500 AMI Semiconductor / ON Semiconductor MOSFET N-CH 55V 75A TO-247</p>	 <p>FDH600_T50A Fairchild/ON Semiconductor DIODE GEN PURP 50V 200MA DO35</p>	 <p>FDH5500 Fairchild/ON Semiconductor MOSFET N-CH 55V 75A TO-247</p>	 <p>FDH600_T50A AMI Semiconductor / ON Semiconductor DIODE GEN PURP 50V 200MA DO35</p>

heiße Teile

Mehr

⊗ 04023C471KAT2A	↔ 08055A870FAT2A	⇒ 08055C102JAT2P	D 70MT60KB	⇒ BHS24-15D0.5A
⊣ BU24590-8H	⊗ BZD27-C120	D BZX585-C68	⇒ CAT660EPA-B1	⇒ CGA2B2X8R2A151K050BE
⊗ CGA3E2X7R1H222M080AD	⊣ CY7B991V-2JC	⊗ FDH038AN08A1	↔ FDH038AN08A1	⇒ FDH047AN08A0
D FDH047AN08A0	⊗ FDH047AN08A0	⊣ FDH055N15A	⊗ FDH055N15A	⇒ FDH15N50
⇒ FDH15N50	↔ FDH210AN08	⊗ FDH210N08	⊣ FDH210N08	⇒ FDH27N50
↔ FDH27N50	⇒ FDH300A.TR	D FDH3369C	⊗ FDH44N50	⊣ FDH44N50
⊗ FDH45N50F	D FDH50N50	⇒ FDH50N50	↔ FDH50N50_F133	⇒ FT1500EY-24
⊣ GPY0029B-EE011	⊗ GRM1555C1H3R7CZ01D	↔ LTC3405AES6-1.5#TRPBF	⇒ MBB02070C1543FCT00	⇒ MC10E1651FN
⊗ MCC25-12I01	⊣ MLK0603L1N8ST000	⊗ R0878LS16L	D SG9033-004	⇒ SM5023BNEH-G-EL
↔ SN74153N	⊗ SPX431LAM1	⊣ TC7MBL3253CFTG	⊗ UMK105CG2R2CW-F	⇒ VE-JNY-MZ

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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